

UVEPROM AS27C256

256K UVEPROM

UV Erasable Programmable Read-Only Memory

AVAILABLE AS MILITARY SPECIFICATIONS

• -55C to 125C operation

- MILITARY Processing Method MIL-PRF-38535, Class Q
- Commercial Version Available

FEATURES

- Organized 32,768 x 8
- Single $+5V \pm 10\%$ power supply
- Pin-compatible with existing 256K ROM's and EPROM's
- All inputs/outputs fully TTL compatible
- Power-saving CMOS technology
- Very high-speed FLASHRITE Pulse Programming
- 3-state output buffers
- 400-mV DC assured noise immunity with standard TTL loads
- Latchup immunity of 250 mA on all input and output pins
- Low power dissipation (CMOS Input Levels)
 -Active 165mW Worst Case
 -Standby 1.7mW Worst Case (CMOS-input levels)
- * FUTURE High Speed Offerings: 55ns, 70ns, 90ns

OPTIONS

MARKING

-70

-90

• Timing

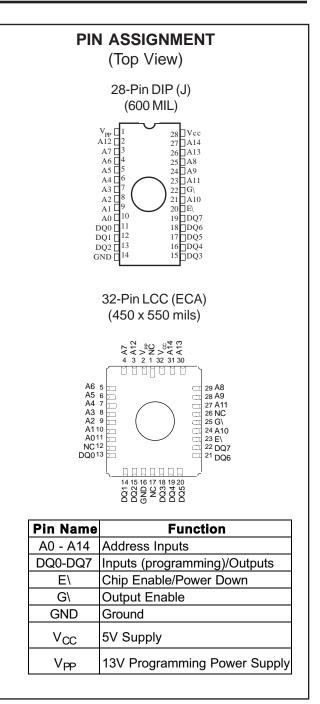
Timing	
120ns access	-12
150ns access	-15
170ns access	-17
200ns access	-20
250ns access	-25
300ns access	-30
55ns access	-55

90ns access

70ns access

I achage(s)		
Ceramic DIP (600mils)	J	No. 110
Ceramic LCC (450 x 550	mils) ECA No. 208

• **Processing / Operating Temperature Ranges** Full Military (-55°C to +125°C) M Industrial (-40°C to +85°C) I Military Temp (-55°C to +125°C) XT



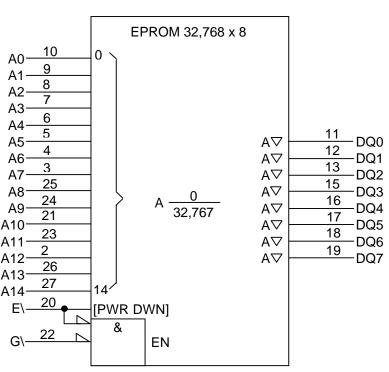
For more products and information please visit our web site at www.austinsemiconductor.com



GENERAL DESCRIPTION

The AS27C256 series is a set of 262,144 bit, ultraviolet-light erasable, electrically programmable read-only memories. These devices are fabricated using power-saving CMOS technology for high speed and simple interface with MOS and bipolar circuits. All inputs (including program data inputs) can be driven by Series 54 TTL circuits without the use of external pullup resistors. Each output can drive one Series 54 TTL circuit without external resistors. The data outputs are 3-state for connecting multiple devices to a common bus. The AS27C256 is pin-compatible with 28-pin 256K ROMs and EPROMs. It is offered in a 600mil dual-in-line ceramic package (J suffix) and a 450 x 550 mil ceramic LCC (ECA suffix) rated for operation from -55°C to 125°C.

Because this EPROM operates from a single 5V supply (in the read mode), it is ideal for use in microprocessor-based systems. One other supply (12.75V) is needed for programming. All programming signals are TTL level. This device is programmable by the AMD FLASHRITE Pulse programming algorithm. The FLASHRITE Pulse programming algorithm uses a $V_{\rm PP}$ of 12.75VV and a $V_{\rm CC}$ of 6.25V for a nominal programming time of four seconds. For programming outside the system, existing EPROM programmers can be used. Locations can be programmed singly, in blocks, or at random.



FUNCTIONAL BLOCK DIAGRAM*

* This symbol is in accordance with ANSI/IEEE std 91-1984 and IEC Publication 617-12.



OPERATION

The seven modes of operation for the AS27C256 are listed in Table 1. The read mode requires a single 5V supply. All inputs are TTL level except for V_{pp} during programming (12.75V for FLASHRITE Pulse), and (12V) on A9 for signature mode.

FUNCTION				MODE [*]	*			
(PINS)	READ	OUTPUT DISABLE	STANDBY	PROGRAMMING	VERIFY	PROGRAM INHIBIT	SIGNATU	RE MODE
E\	V_{IL}	V _{IL}	V _{IH}	V _{IL}	V _{IH}	V _{IH}	V	, IL
G\	V_{IL}	V _{IH}	Х	V _{IH}	V_{IL}	Х	V	, IL
V _{PP}	X ¹	X ¹	X ¹	V _{PP}	V _{PP}	V _{PP}	V	CC
V _{CC}	V _{CC}	V _{CC}	V _{CC} +/3V	V _{CC}	V_{CC}	V _{CC}	V	CC
A9	Х	Х	Х	Х	Х	Х	V_{ID}^{2}	V _{ID} ²
A0	Х	Х	Х	х	Х	Х	V_{IL}	V _{IH}
							COI	DE**
DQ0-DQ7	Data Out	High-Z	High-Z	Data In	Data Out	High-Z	MFG	DEVICE
							01h	10h

TABLE 1. OPERATION MODES

¹For normal standby & read operation, VPP is Don't Care X.

 2 V_{ID} = 12V +/- .5V

NOTES:

* X can be $\mathbf{V}_{_{\rm I\!L}}$ or $\mathbf{V}_{_{\rm I\!H}}$

** Die is AMD. User can program on benchtop programmer by selecting AM27C256 from the device type selection menu.



READ/OUTPUT DISABLE

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When the outputs of two or more AS27C256 are connected in parallel on the same bus, the output of any particular device in the circuit can be read with no interference from the competing outputs of the other devices. To read the output of the selected AS27C256, a low-level signal is applied to $E \setminus \text{and } G \setminus$. All other devices in the circuit should have their outputs disabled by applying a high-level signal to one of these pins. Output data is accessed at pins DQ0 through DQ7.

LATCHUPIMMUNITY

Latchup immunity on the AS27C256 is a minimum of 250mA on all inputs and outputs. This feature provides latchup immunity beyond any potential transients at the printed circuit board level when the EPROM is interfaced to industry standard TTL or MOS logic devices. Input/output layout approach controls latchup without compromising performance or packing density.

POWER DOWN

Active I_{CC} supply current can be reduced from 25mA (AS27C256-12 through AS27C256-25) to 1mA (TTL-level inputs) or 300 μ A (CMOS-level inputs) by applying a high TTL/CMOS signal to the E\ pin. In this mode all outputs are in the high-impedance state.

ERASURE

Before programming, the AS27C256 is erased by exposing the chip through the transparent lid to a high-intensity ultraviolet light (wavelength 2537 Å). EPROM erasure before programming is necessary to ensure that all bits are in the logic-high state. Logic-lows are programmed into the desired locations. A programmed logic-low can be erased only by ultraviolet light. The recommended minimum exposure dose (UV intensity x exposure time) is $15W \cdot s/cm^2$. A typical $12mW/cm^2$, filterless UV lamp erases the device in 21 minutes. The lamp should be located about 2.5cm above the chip during erasure. After erasure, all bits are in the high state. It should be noted that normal ambient light contains the correct wavelength for erasure; therefore, when using the AS27C256, the window should be covered with an opaque label.

FLASHRITE PULSE PROGRAMMING

The AS27C256 EPROM is programmed by using the AMD FLASHRITE Pulse programming algorithm as illustrated by the flowchart in Figure 1. This algorithm programs the device in a nominal time of 4 seconds. Actual programming time varies as a function of the programmer used.

Data is presented in parallel (eight bits) on pins DQ0 to DQ7. Once addresses and data are stable, $E \setminus is pulsed$.

The FLASHRITE Pulse programming algorithm uses initial pulses of 100 microseconds (μ s) followed by a byte-verification step to determine when the addressed byte has been successfully programmed. Up to 25 100 μ s pulses per byte are provided before a failure is recognized.

The programming mode is achieved when $V_{pp} = 12.75V$, $V_{CC} = 6.25V$, $G \mid = V_{IH}$, and $E \mid = V_{IL}$. More than one device can be programmed when the devices are connected in parallel. Locations can be programmed in any order. When the AMD FLASHRITE Pulse programming routine is completed, all bits are verified with $V_{CC} = V_{pp} = 5V$.

PROGRAM INHIBIT

Programming can be inhibited by maintaining a high-level input on $E\!\!\setminus\!\!.$

PROGRAM VERIFY

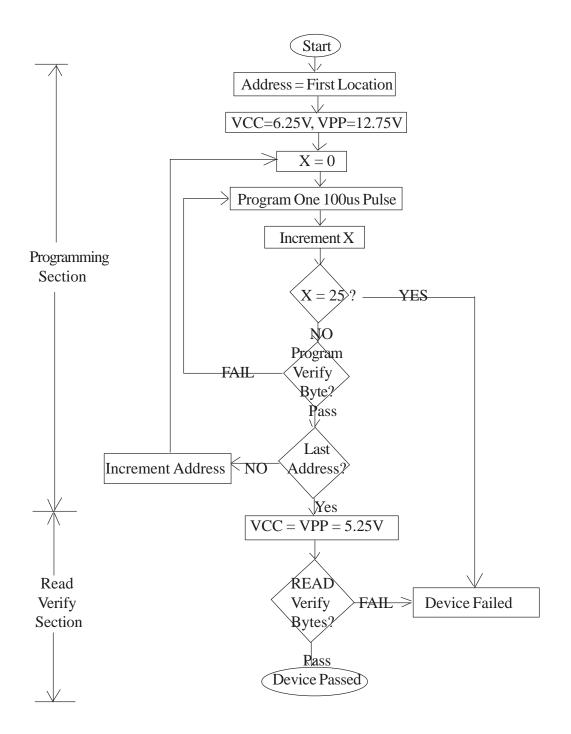
Programmed bits can be verified with V_{PP} = 12.75V when $~G \backslash = V_{IL},$ and $E \backslash = V_{IH}.$

SIGNATURE MODE

The signature mode provides access to a binary code identifying the manufacturer and device type. This mode is activated when A9 is forced to $12V \pm 0.5V$. Two identifier bytes are accessed by A0 (terminal 10); i.e., $A0=V_{IL}$ accesses the manufacturer code, which is output on DQ0-DQ7; $A0=V_{IH}$ accesses the device code, which is also output on DQ0-DQ7. All other addresses must be held at VIL. Each byte contains odd parity on bit DQ7. The manufacturer code for these devices is 01h and the device code is 10h.



FIGURE 1. FLASHRITE PULSE PROGRAMMING FLOWCHART





UVEPROM AS27C256

Austin Semiconductor, Inc.

ABSOLUTE MAXIMUM RATINGS*

Supply Voltage Range, V_{CC}^{**} 0.6V to +7.0V
Supply Voltage Range, V ^{**} _{pp} **0.6V to +13.5V
Input Voltage Range, All inputs except A9**0.6V to +6.0V
A90.6V to +13.5V
Output Voltage Range**0.6V to V _{CC} +.6V
Minimum Operating Free-air Temperature, T _A 55°C
Maximum Operating Case Temperature, T _C 125°C
Storage Temperature Range, T _{stg} 65°C to 150°C

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

** All voltage values are with respect to GND.

				MIN	TYP	MAX
V _{CC}	Supply Voltage	Read Mode ¹		4.5	5	5.5
•00	ouppij voltago	FLASHRITE Pulse program	nming algorithm	6	6.25	6.5
V _{PP}	Supply Voltage	Read Mode ²				V _{CC} -0.6
• • • •	eupply relage	FLASHRITE Pulse program	LASHRITE Pulse programming algorithm			13
V	High lovel input ve	Itaga	TTL inputs	2.2		V _{CC} +.6
V _{IH}	rigii-level liiput vo	High-level input voltage CMOS inputs		V _{CC} -0.2		V _{CC} +.6
VIL	Low-level input vol	tano	TTL inputs	-0.5		0.8
۷IL		lage	CMOS inputs	-0.5		0.2
V _{ID}	Voltage level on As	level on A9 for signature mode		11.5	12	12.5
Τ _Α	Operating free-air	temperature		-55		
Т _С	Operating case ter	nperature				+125

RECOMMENDED OPERATING CONDITIONS

NOTES:

1. V_{cc} must be applied before or at the same time as V_{pp} and removed after or at the same time as V_{pp} . The deivce must not be inserted into or removed from the board when V_{pp} or V_{cc} is applied.

2. V_{pp} can be connected to V_{cc} directly (except in the program mode). V_{cc} supply current in this case would be $I_{cc2} + I_{pp1}$.

ELECTRICAL CHARACTERISTICS OVER RECOMMENDED RANGES OF SUPPLY VOLTAGE AND OPERATING FREE-AIR TEMPERATURE

	PARAMETER		TEST CONDITIONS	MIN	TYP ¹	MAX	UNIT
V _{OH}	High-level output voltage		Ι _{ΟΗ} = -400μΑ	2.4			V
V _{OL}	Low-level output voltage		I _{OL} = 2.1mA			0.4	V
I _I	Input current (leakage)		V _I = 0V to 5.5V			±1	μA
Ι _Ο	Output current (leakage)		V_{O} = 0V to V_{CC}			±5	μA
I _{PP1}	V _{PP} supply current		V _{PP} = V _{CC} = 5.5V			100	μA
I _{PP2}	V _{PP} supply current (during program pulse) ²		V _{PP} = 13V		30	50	mA
	(august (standby)	TTL-Input Level	V _{CC} = 5.5V, E\=V _{IH}			1	mA
I _{CC1}	V _{CC} supply current (standby)	CMOS-Input Level	V _{CC} = 5.5V, E\=V _{CC}			300	μA
I _{CC2}	V _{CC} supply current (active)	'27C256-12 '27C256-15 '27C256-17 '27C256-20,-25	E\=V _{IL} , V _{CC} =5.5V t _{cycle} = minimum, outputs open		15	25	mA
		•					

NOTES:

^{1.} Typical values are at $T^{}_{\rm A}{=}25^\circ C$ and nominal voltages.

^{2.} This parameter has been characterized at 25°C and is not tested.



CAPACITANCE OVER RECOMMENDED RANGES OF SUPPLY VOLTAGE AND OPERAT-ING FREE-AIR TEMPERATURE, f = 1MHz*

	Р	ARAMETER	TEST CONDITIONS	TYP**	MAX	UNIT
С	, i	Input capacitance	$V_I = 0V$	6	10	pF
C	o	Output capacitance	$V_{O} = 0V$	10	14	pF

* Capacitance measurements are made on a sample basis only.

** Typical values are at $T_A = 25^{\circ}C$ and nominal voltages.

SWITCHING CHARACTERISTICS OVER RECOMMENDED RANGES OF SUPPLY VOLT-AGE AND OPERATING FREE-AIR TEMPERATURE^{1,2}

	PARAMETER		TEST		-12		-1	UNIT
			MIN	MAX	MIN	MAX	UNIT	
t _{a(A)}	Access time from address	see Figure 2		120		150	ns	
t _{a(E)}	Access time from E\			120		150	ns	
t _{en(G)R}	Output enable time from G\			40		50	ns	
t _{dis}	Disable time of output from G\ or E whichever occurs first ³		0	30	0	30	ns	
t _{v(A)}	Output data valid time after change of address, E or G whichever occurs first ³		0		0		ns	

PARAMETER		TEST	-17		-20		-25		
		CONDITIONS ^{1, 2}	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{a(A)}	Access time from address	see Figure 2		170		200		250	ns
t _{a(E)}	Access time from E\			170		200		250	ns
t _{en(G)R}	Output enable time from G\			50		60		60	ns
t _{dis}	Disable time of output from G\ or E whichever occurs first ³		0	40	0	50	0	60	ns
t _{v(A)}	Output data valid time after change of address, E or G whichever occurs first ³		0		0		0		ns

NOTES:

1.Timing measurements are made at 2V for logic high and 0.8V for logic low (see figure 2).

2. Common test conditions apply for t_{dis} except during programming.

3. Value calculated from 0.5V delta to measured output level. This parameter is only sampled and not 100% tested.

SWITCHING CHARACTERISTICS FOR PROGRAMMING: $V_{cc} = 6.5V$ and $V_{pp} = 12.75V$ (AMD FLASHRITE ALGO), $T_{a} = 25^{\circ}C$

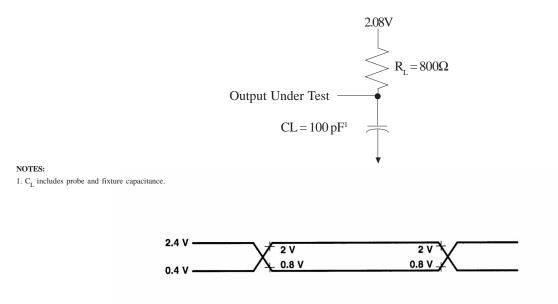
PARAMETER		MIN	MAX	UNIT
t _{dis(G)}	Output disable time from G\	0	130	ns
t _{en(G)W}	Output enable time from G\		150	ns



RECOMMENDED TIMING REQUIREMENTS FOR PROGRAMMING: $V_{CC} = 6.5$ and $V_{PP} = 12.75V$ (AMD FLASHRITE ALGO), $T_A = 25$ °C (See Figure 2)

		MIN	TYP	MAX	UNIT
t _{h(A)}	Hold Time, Address	0			μs
t _{h(D)}	Hold Time, Data	2			μs
t _{w(E)PR}	Pulse Duration, Initial Program	95	100	105	μs
t _{su(A)}	Setup Time, Address	2			μs
t _{su(G)}	Setup Time, G\	2			μs
t _{su(E)}	Setup Time, E\	2			μs
t _{su(D)}	Setup Time, Data	2			μs
t _{su(VPP)}	Setup Time, V _{PP}	2			μs
t _{su(VCC)}	Setup Time, V _{CC}	2			μs

PARAMETER MEASUREMENT INFORMATION



The AC testing inputs are driven at 2.4V for logic high and 0.4V for logic low. Timing measurements are made at 2V for logic high and 0.8V for logic low for both inputs and outputs.

FIGURE 2. LOAD CIRCUIT AND VOLTAGE WAVEFORMS





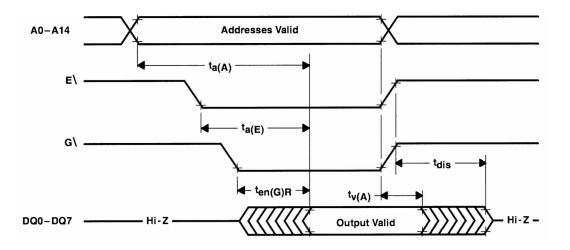
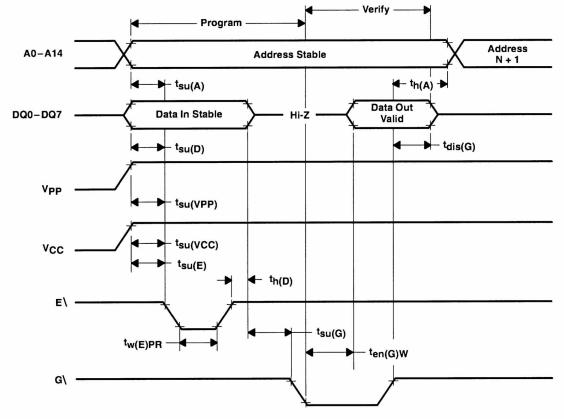


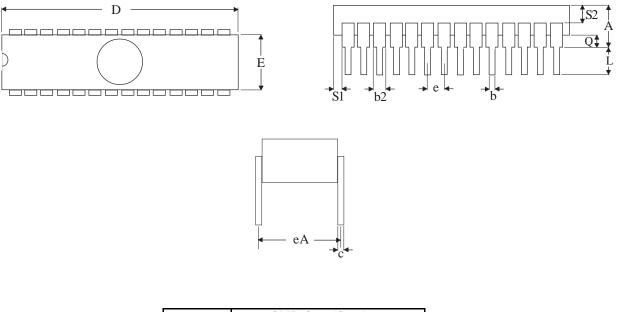
FIGURE 4. PROGRAM-CYCLE TIMING (FLASHRITE PULSE PROGRAMMING)





MECHANICAL DEFINITION*

ASI Case #110 (Package Designator J)



	SMD Specifications		
Symbol	MIN	MAX	
A		0.232	
b	0.014	0.026	
b2	0.045	0.065	
С	0.008	0.018	
D		1.490	
E	0.500	0.610	
eA	0.600 BSC		
е	0.100 BSC		
L	0.125	0.200	
Q	0.015	0.060	
S1	0.005		
S2	0.005		

*All measurements are in inches.

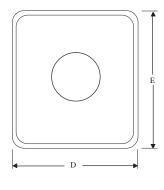
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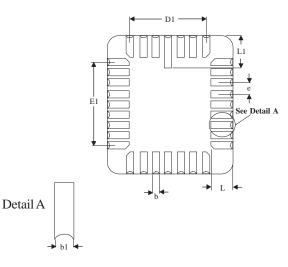
SEMICONDUCTOR

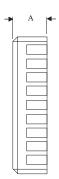


MECHANICAL DEFINITIONS*

ASI Case #208 (Package Designator ECA)







UVEPROM

AS27C256

	SMD SPECIFICATIONS		
SYMBOL	MIN	MAX	
А	0.060	0.120	
b	0.022	0.028	
b1	0.006	0.022	
D	0.442	0.458	
D1	0.300 BSC		
E	0.540	0.560	
E1	0.400	BSC	
е	0.050 BSC		
L	0.045	0.055	
L1	0.075	0.095	

*All measurements are in inches.



ORDERING INFORMATION

EXAMPLE: AS27C256-30JM/MIL Package Type **Device Number** Speed **Operating Temp.** AS27C256 -55 J -70 * AS27C256 J AS27C256 -90 J AS27C256 -12 J AS27C256 -15 J AS27C256 -17 J AS27C256 -20 J AS27C256 -25 J AS27C256 -30 J

EXAMPLE: AS27C256-15ECAM

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SEMICONDUCTOR

Device Number	Speed	Package Type	Operating Temp.
AS27C256	-55	ECA	*
AS27C256	-70	ECA	*
AS27C256	-90	ECA	*
AS27C256	-12	ECA	*
AS27C256	-15	ECA	*
AS27C256	-17	ECA	*
AS27C256	-20	ECA	*
AS27C256	-25	ECA	*
AS27C256	-30	ECA	*

***PROCESS / OPERATING TEMPERATURE**

M = Full Military Processing Per	-55°C to +125°C
MIL-PRF-3835, Class Q	
I = Industrial Temperature Range	-40° C to $+85^{\circ}$ C
XT = Military Temperature Range	-55°C to +125°C

UVEPROM AS27C256



SMD ORDERING INFORMATION

SMD	ASI PN	SPEED	PACKAGE
5962-8606301XA	AS27C256 -20JM	200ns	600mil, 28LD. DIP
5962-8606311XA	AS27C256 -20JM	200ns	600mil, 28LD. DIP
5962-8606302XA	AS27C256 -25JM	250ns	600mil, 28LD. DIP
5962-8606312XA	AS27C256 -25JM	250ns	600mil, 28LD. DIP
5962-8606303XA	AS27C256 -30JM	300ns	600mil, 28LD. DIP
5962-8606313XA	AS27C256 -30JM	300ns	600mil, 28LD. DIP
5962-8606304XA	AS27C256 -17JM	170ns	600mil, 28LD. DIP
5962-8606314XA	AS27C256 -17JM	170ns	600mil, 28LD. DIP
5962-8606305XA	AS27C256 -15JM	150ns	600mil, 28LD. DIP
5962-8606315XA	AS27C256 -15JM	150ns	600mil, 28LD. DIP
5962-8606306XA	AS27C256 -12JM	120ns	600mil, 28LD. DIP
5962-8606316XA	AS27C256 -12JM	120ns	600mil, 28LD. DIP
5962-8606307XA	AS27C256 -90JM	90ns	600mil, 28LD. DIP
5962-8606317XA	AS27C256 -90JM	90ns	600mil, 28LD. DIP
5962-8606308XA	AS27C256 -70JM	70ns	600mil, 28LD. DIP
5962-8606318XA	AS27C256 -70JM	70ns	600mil, 28LD. DIP
5962-8606309XA	AS27C256 -55JM	55ns	600mil, 28LD. DIP
5962-8606319XA	AS27C256 -55JM	55ns	600mil, 28LD. DIP
SMD	ASI PN	SPEED	PACKAGE
SMD 5962-8606301YA	ASI PN AS27C256 -20ECA	SPEED 200ns	PACKAGE 32-LD. 0.450 x 0.550, LCC
5962-8606301YA	AS27C256 -20ECA	200ns	32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA	AS27C256 -20ECA AS27C256 -20ECA	200ns 200ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA	200ns 200ns 250ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA	200ns 200ns 250ns 250ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA 5962-8606303YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA	200ns 200ns 250ns 250ns 300ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA 5962-8606303YA 5962-8606313YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA AS27C256 -30ECA	200ns 200ns 250ns 250ns 300ns 300ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA 5962-8606303YA 5962-8606313YA 5962-8606304YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA AS27C256 -30ECA AS27C256 -17ECA	200ns 200ns 250ns 250ns 300ns 300ns 170ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA 5962-8606303YA 5962-8606313YA 5962-8606304YA 5962-8606314YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA AS27C256 -30ECA AS27C256 -17ECA AS27C256 -17ECA	200ns 200ns 250ns 250ns 300ns 300ns 170ns 170ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA 5962-8606303YA 5962-8606313YA 5962-8606304YA 5962-8606314YA 5962-8606305YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA AS27C256 -30ECA AS27C256 -17ECA AS27C256 -17ECA AS27C256 -15ECA	200ns 200ns 250ns 250ns 300ns 300ns 170ns 170ns 150ns	 32-LD. 0.450 x 0.550, LCC
5962-8606301YA 5962-8606311YA 5962-8606302YA 5962-8606312YA 5962-8606303YA 5962-8606313YA 5962-8606304YA 5962-8606314YA 5962-8606305YA 5962-8606315YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA AS27C256 -30ECA AS27C256 -17ECA AS27C256 -17ECA AS27C256 -15ECA AS27C256 -15ECA	200ns 200ns 250ns 250ns 300ns 300ns 170ns 170ns 150ns 150ns	32-LD. 0.450 x 0.550, LCC 32-LD. 0.450 x 0.550, LCC
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5962-8606301YA 5962-8606302YA 5962-8606302YA 5962-8606303YA 5962-8606303YA 5962-8606303YA 5962-8606304YA 5962-8606305YA 5962-8606305YA 5962-8606305YA 5962-8606315YA 5962-8606317YA 5962-8606308YA 5962-8606308YA 5962-8606318YA	AS27C256 -20ECA AS27C256 -20ECA AS27C256 -25ECA AS27C256 -25ECA AS27C256 -30ECA AS27C256 -30ECA AS27C256 -17ECA AS27C256 -17ECA AS27C256 -15ECA AS27C256 -15ECA AS27C256 -12ECA AS27C256 -12ECA AS27C256 -90ECA AS27C256 -90ECA AS27C256 -70ECA	200ns 200ns 250ns 250ns 300ns 170ns 170ns 150ns 150ns 120ns 120ns 90ns 90ns 70ns 70ns	$\begin{array}{c} 32\text{-LD.} \ 0.450 \times 0.550, \ LCC\\ 32\text{-LD.} \ 0.450 \times 0.550, \ LCC\\$